ABSTRACT

A system and method for the fabrication of high reliability capacitors (1011), inductors (1012), and multilayer interconnects (1013) (including resistors (1014)) on various thin film hybrid substrate surfaces (0501) is The disclosed method first employs a thin metal disclosed. substrate layer (0502) deposited and patterned on the This thin patterned layer (0502) is used to provide both lower electrodes for capacitor structures (0603) and interconnects (0604) between upper electrode components. Next, a dielectric layer (0705) is deposited over the thin patterned layer (0502) and the dielectric layer (0705) is patterned to open contact holes (0806) to the thin patterned The upper electrode layers (0907, 0908, 1009, 1010) laver. are then deposited and patterned on top of the dielectric (0705).

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